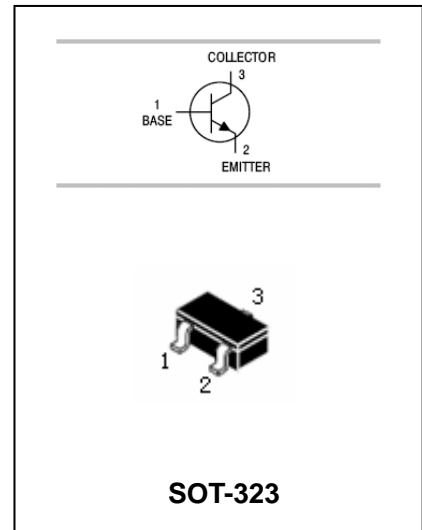


## NPN Silicon Epitaxial Planar Transistor

## S9013W

### FEATURES

- High Collector Current.( $I_C=500\text{mA}$ )
- Complementary To S9012.
- Excellent  $H_{FE}$  Linearity.
- Power dissipation.( $P_T=200\text{mW}$ )



### APPLICATIONS

- High Collector Current.

### ORDERING INFORMATION

Type No.	Marking	Package Code
S9013W	J3	SOT-323

### MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	40	V
$V_{CEO}$	Collector-Emitter Voltage	25	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current -Continuous	500	mA
$P_C$	Collector Dissipation	200	mW
$T_j, T_{stg}$	Junction and Storage Temperature	-55~150	$^\circ\text{C}$

**NPN Silicon Epitaxial Planar Transistor****S9013W****ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu A, I_E=0$	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=0.1mA, I_B=0$	25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu A, I_C=0$	5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=40V, I_E=0$			0.1	$\mu A$
Collector cut-off current	$I_{CEO}$	$V_{CE}=20V, I_B=0$			0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=5V, I_C=0$			0.1	$\mu A$
DC current gain	$h_{FE}$	$V_{CE}=1V, I_C=50mA$	120		400	
		$V_{CE}=1V, I_C=500mA$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=500mA, I_B=50mA$			0.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=500mA, I_B=50mA$			1.2	V
Transition frequency	$f_T$	$V_{CE}=6V, I_C=20mA$ $f=30MHz$	150			MHz

**CLASSIFICATION OF  $h_{FE(1)}$** 

Rank	L	H	J
Range	120-200	200-350	300-400

## NPN Silicon Epitaxial Planar Transistor

### S9013W

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

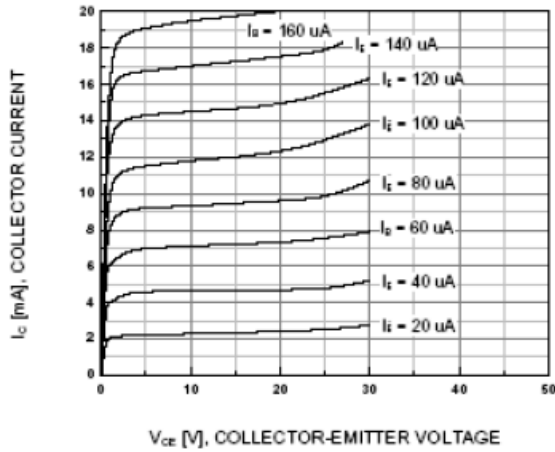


Figure 1. Static Characteristic

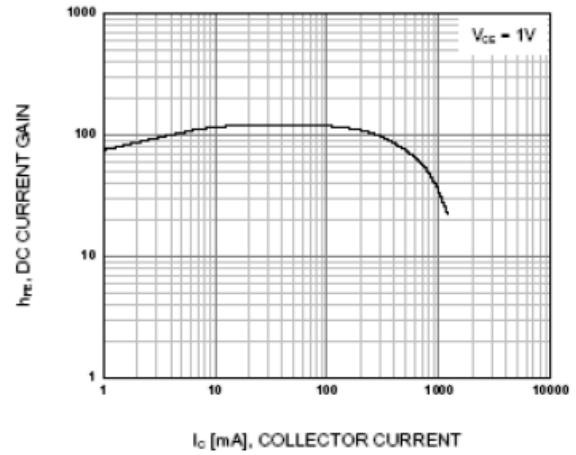


Figure 2. DC current Gain

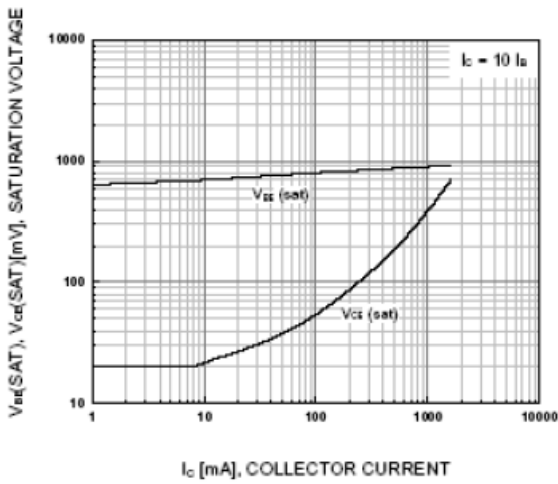


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

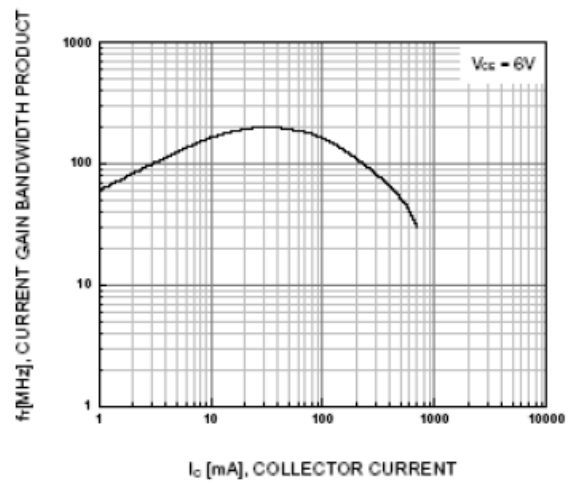


Figure 4. Current Gain Bandwidth Product

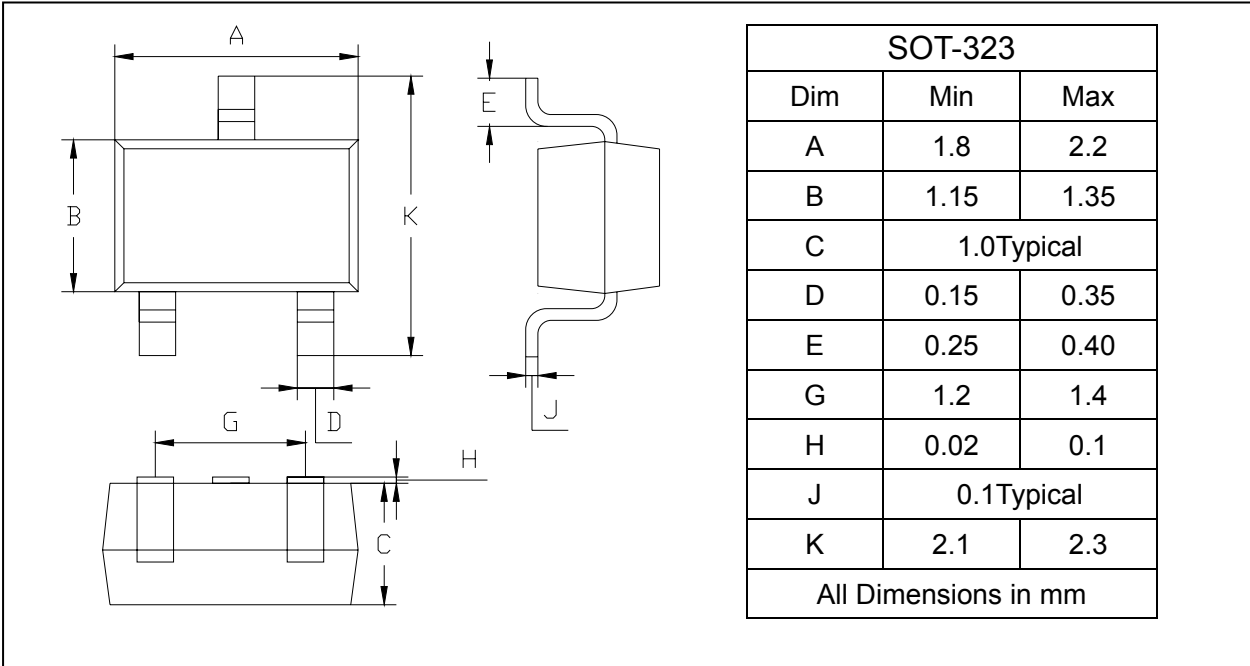
## NPN Silicon Epitaxial Planar Transistor

## S9013W

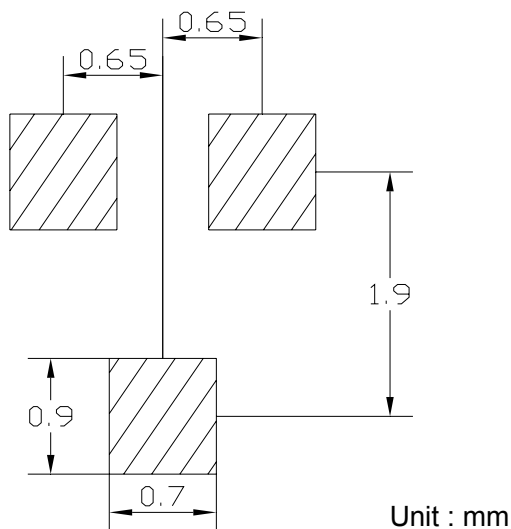
### PACKAGE OUTLINE

Plastic surface mounted package

SOT-323



### SOLDERING FOOTPRINT



### PACKAGE INFORMATION

Device	Package	Shipping
S9013W	SOT-323	3000/Tape&Reel

[www.s-manuals.com](http://www.s-manuals.com)